Attorney Docket No.: AMD-AF01210

Declaration and Power of Attorney for a Patent Application

Declaration

the specification of which:

As below named inventor, I hereby declare that my residence post office address, and citizenship are as stated below my name. Further, I hereby declare that I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

IMPROVING ELECTROSTATIC DISCHARGE PERFORMANCE OF A SILICON STRUCTURE AND EFFICIENT USE OF AREA WITH ELECTROSTATIC DISCHARGE PROTECTIVE DEVICE UNDER THE PAD APPROACH AND ADJUSTMENT OF VIA CONFIGURATION THERETO TO CONTROL DRAIN JUNCTION RESISTANCE

x is attached hereto, or was filed on was amended on	as application serial no.		: and	
I hereby state that I have reviewed a the claims, as amended by any amer			tified specification, including	
I acknowledge the duty to disclose intaccordance with Title 37, Code of Fe			of this application in	
Foreign Priority Claim				
I hereby claim foreign priority benefits for patent or inventor's certificate liste inventor's certificate having a filing da	ed below and have also ider	ntified below any fo	reign application for patent of	
Number Country	Date Filed	Priority Claimed		
		yes	no	
		yes	no	
U.S. Priority Claim				
I hereby claim the benefit under Title application(s) listed below and, insofa in the prior United States application Section 112, I acknowledge the duty Regulations, Section 1.56(a) which of PCT international filing date of this applications.	ar as the subject matter of ear in the manner provided by to to disclose material informatic accurred between the filing of	ach of the claims o he first paragraph ition as defined in	fthis application is not disclo of Title 35, United States Co Title 37, Code of Federal	sec de,
Serial Number Filin	g Date Status	(patented/pending	g/abandoned)	
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rev. 10/00 kgr

Power of Attorn y

As a named inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent Trademark Office connected therewith.

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I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section

Attorney Docket No.: AMD-AF01210

1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

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